

Vishay Siliconix

RoHS

COMPLIANT HALOGEN

FREE

Available

Dual N-Channel 30-V (D-S) MOSFET with Schottky Diode

PRODUCT SUMMARY					
V _{DS} (V)	R_{DS(on)} (Ω)	I _D (A)			
30	0.022 at $V_{GS} = 10 V$	7.5			
	0.030 at $V_{GS} = 4.5 V$	6.5			

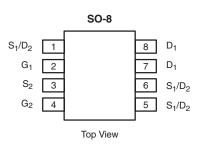
SCHOTTKY PRODUCT SUMMARY					
V _{DS} (V)	V _{SD} (V) Diode Forward Voltage	I _F (A)			
30	0.50 at 1 A	2.0			

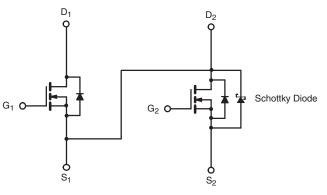
FEATURES

- Halogen-free According to IEC 61249-2-21
 Definition
- LITTLE FOOT[®] Plus Schottky
- Si4830DY Pin Compatible
- PWM Optimized
- 100 % R_g Tested
- Compliant to RoHS Directive 2002/95/EC

APPLICATIONS

Asymmetrical Buck-Boost DC/DC Converter





Ordering Information: Si4830ADY-T1-E3 (Lead (Pb)-free) Si4830ADY-T1-GE3 (Lead (Pb)-free and Halogen-free)

N-Channel MOSFET

N-Channel MOSFET

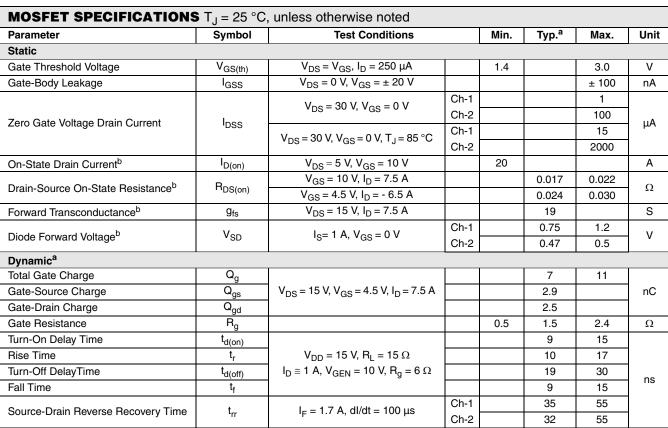
ABSOLUTE MAXIMUM RATINGS T	_A = 25 °C, unle	ess otherwise r	noted			
Parameter		Symbol	10 s	Steady State	Unit	
Drain-Source Voltage		V _{DS}	30		V	
Gate-Source Voltage		V _{GS}	± 20		v	
Continuous Drain Querent (T. 150 °C)a	T _A = 25 °C	1_	7.5	5.7		
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C	۱D	7.5 5.7 6.0 4.6 30	А		
Pulsed Drain Current	<u>.</u>	I _{DM}	;	30	A	
Continuous Source Current (Diode Conduction) ^a		۱ _S	1.7	0.9		
Maximum Davier Dissingtional	T _A = 25 °C	PD	2.0 1.1		W	
Maximum Power Dissipation ^a	T _A = 70 °C	' D	1.3	0.7	vv	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C	

THERMAL RESISTANCE RATINGS								
			MOSFET		SCHOTTKY			
Parameter		Symbol	Тур.	Max.	Тур.	Max.	Unit	
Maximum Junction-to-Ambient ^a	t ≤ 10 s	R _{thJA}	52	62.5	53	62.5		
	Steady State		93	110	93	110		
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	35	40	35	40	°C/W	

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

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Notes:

a. Guaranteed by design, not subject to production testing.

b. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %.

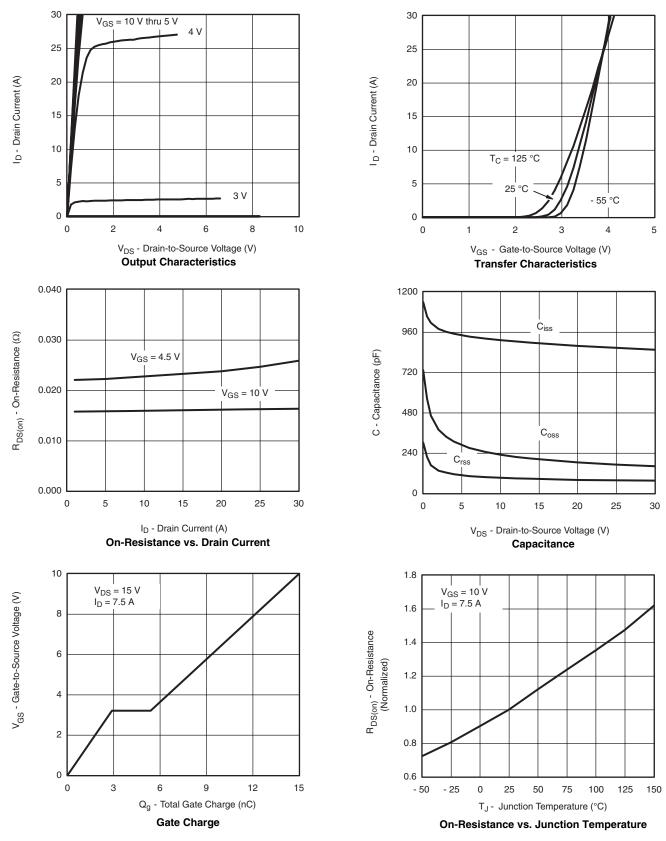
SCHOTTKY SPECIFICATIONS $T_J = 25 \text{ °C}$, unless otherwise noted									
Parameter	Symbol	Test Conditions	Max.	Unit					
Forward Voltage Drop	V _F	I _F = 1.0 A		0.47	0.50	V			
		I _F = 1.0 A, T _J = 125 °C		0.36	0.42				
Maximum Reverse Leakage Current		V _R = 30 V		0.004	0.100				
	I _{rm}	V _R = 30 V, T _J = 100 °C		0.7	0.100	mA			
		$V_{R} = -30$ V, $T_{J} = 125$ °C		3.0	20				
Junction Capacitance	CT	V _R = 10 V		50		pF			

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



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MOSFET TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

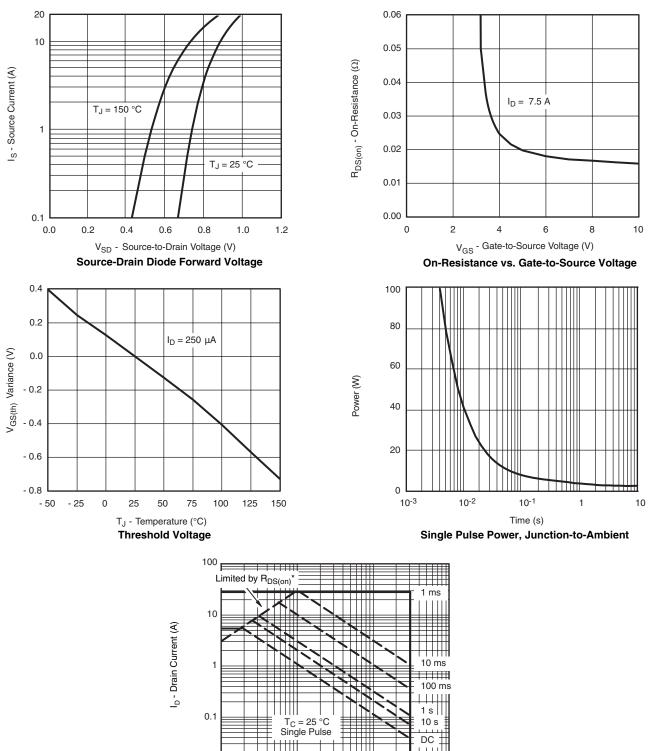


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MOSFET TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

0.01 L 0.1



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 $\label{eq:V_DS} \begin{array}{l} V_{DS} \text{ - Drain-to-Source Voltage (V)} \\ ^*V_{DS} \text{ > minimum } V_{GS} \text{ at which } R_{DS(on)} \text{ is specified} \\ \textbf{Safe Operating Area, Junction-to-Foot} \end{array}$

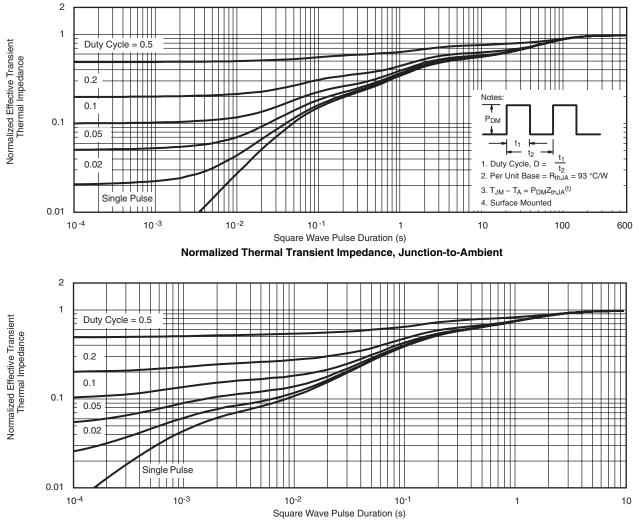
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SHA



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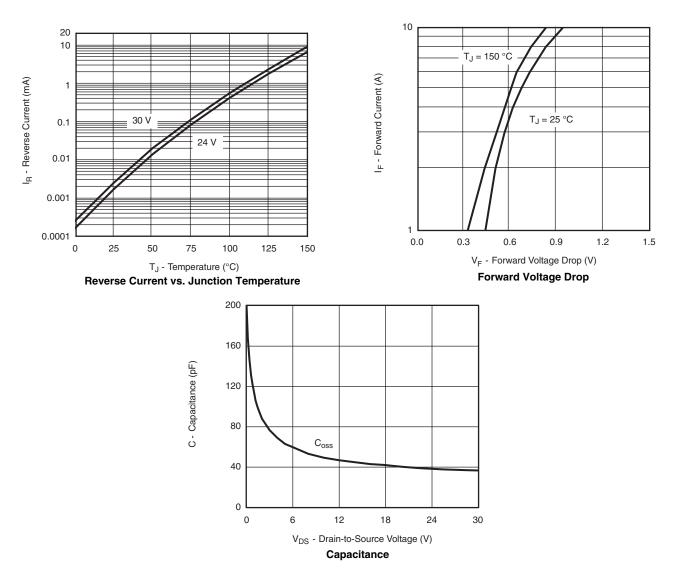




Normalized Thermal Transient Impedance, Junction-to-Foot

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SCHOTTKY TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?72021.



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